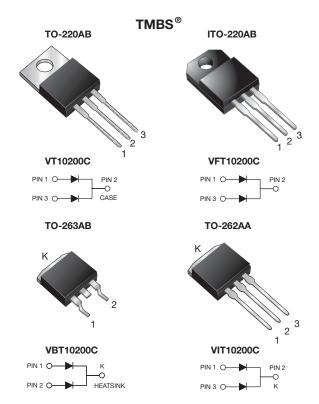


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Trench MOS Barrier Schottky Rectifier

Ultra Low VF = 0.58 V at IF = 2.5 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 5.0 A					
V_{RRM}	200 V					
I _{FSM}	80 A					
V_F at $I_F = 5.0$ A	0.65 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Diode variations	Common cathode					

FEATURES





- · Low forward voltage drop, low power losses
- · High efficiency operation

- RoHS
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	VT10200C	VFT10200C	VBT10200C	VIT10200C	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	200						
Maximum average forward rectified current per device		10.0						
(fig. 1) per diod	e I _{F(AV)}	5.0						
Peak forward surge current 8.3 ms single half sine-way superimposed on rated load per diode	re I _{FSM}	м 80				Α		
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode	E _{AS}	30						
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}\text{C} \pm 2 ^{\circ}\text{C}$ per diode	I _{RRM}	0.5				Α		
Voltage rate of change (rated V _R)	dV/dt	10 000				V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V		
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150						



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	$I_R = 1.0 \text{ mA}$	T _A = 25 °C	V_{BR}	200 (minimum)	=	V		
Instantaneous forward voltage per diode	$I_F = 2.5 A$	T 05 °C	V _F ⁽¹⁾	0.81	-	V		
	I _F = 5.0 A	$T_A = 25 ^{\circ}C$		1.10	1.60			
	$I_F = 2.5 A$	T _A = 125 °C		0.58	-			
	$I_F = 5.0 \text{ A}$			0.65	0.73			
Reverse current per diode	V _R = 180 V	T _A = 25 °C	I _R (2)	1.7	-	μΑ		
		T _A = 125 °C		1.8	-	mA		
	V _R = 200 V	T _A = 25 °C		-	150	μΑ		
		T _A = 125 °C		2.5	10	mA		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 $\,\%$ duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT10200C	VFT10200C	VBT10200C	VIT10200C	UNIT
Typical thermal resistance	per diode	$R_{ hetaJC}$	3.5	7.0	3.5	3.5	°C/W
	per device		2.5	5.5	2.5	2.5	C/VV

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT10200C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VFT10200C-E3/4W	1.72	4W	50/tube	Tube			
TO-263AB	VBT10200C-E3/4W	1.37	4W	50/tube	Tube			
TO-263AB	VBT10200C-E3/8W	1.37	8W	800/reel	Tape and reel			
TO-262AA	VIT10200C-E3/4W	1.44	4W	50/tube	Tube			

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

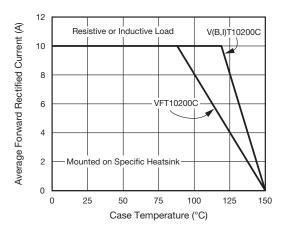


Fig. 1 - Maximum Forward Current Derating Curve

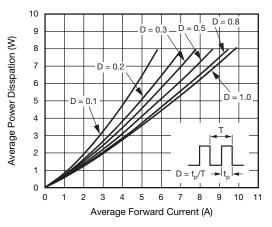


Fig. 2 - Forward Power Loss Characteristics Per Device

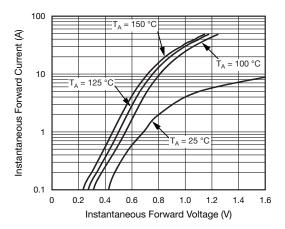


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

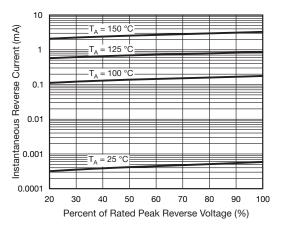


Fig. 4 - Typical Reverse Characteristics Per Diode

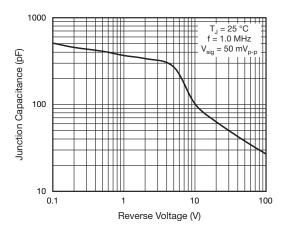


Fig. 5 - Typical Junction Capacitance Per Diode

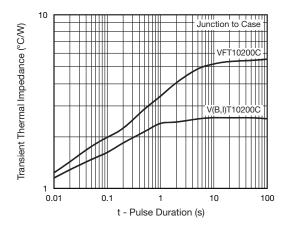
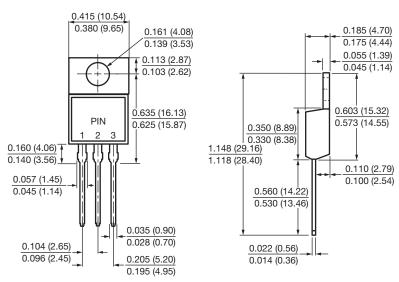


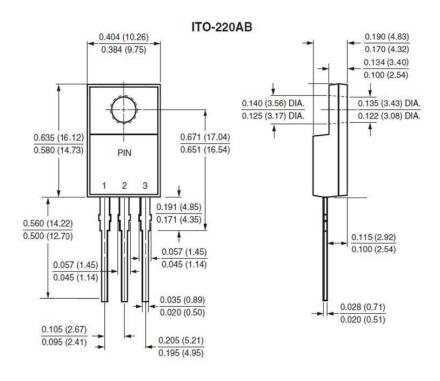
Fig. 6 - Typical Transient Thermal Impedance Per Device

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



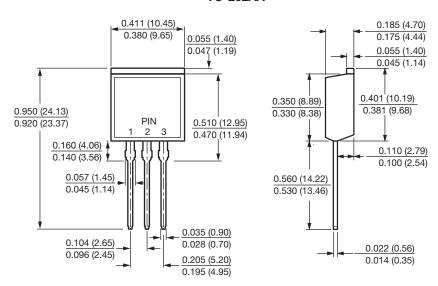




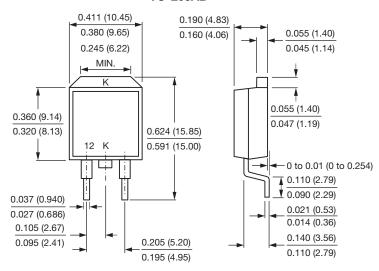
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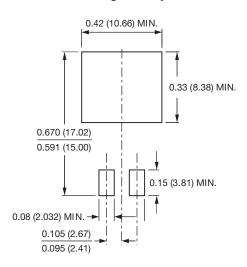
TO-262AA



TO-263AB



Mounting Pad Layout



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